

Digital Transistor(built-in resistors)

Feature

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making the device design easy.

R1 OUT (3) R2 GND (2) R1=4.7ΚΩ R2=47ΚΩ 3 - OUT

Top View

2 - GND

1 - IN

Applications

- Inverter
- Interface
- Driver

Mechanical Characteristics

Lead finish:100% matte Sn(Tin)

Mounting position: Any

Qualified max reflow temperature:260°C

Pure tin plating: 7 ~ 17 um

▶ Pin flatness:≤3mil

Structure

NPN epitaxial planar silicon transistor (Resistor built-in type)

Electrical characteristics per line@25°C(unless otherwise specified)

| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Units |
|----------------------|--------------------------------|---|------|------|------|-------|
| Input voltage | $V_{I(off)}$ | V _{CC} =5V,I _O =100μA | - | - | 0.5 | V |
| | V _{I(on)} | V _O =0.3V,I _O =5mA | 1.3 | ı | - | V |
| Output voltage | $V_{O(off)}$ | I _O /I _I =5mA/0.25mA | - | 0.1 | 0.3 | V |
| Input current | I _I | V _I =5V | - | - | 1.8 | mA |
| Output current | I _{O(off)} | V _{CC} =50V, V _I =0V | - | - | 0.5 | μA |
| DC current gain | G ₁ | V _O =5V, I _O =10mA | 80 | - | - | - |
| Input resistance | R ₁ | - | 3.29 | 4.7 | 6.11 | ΚΩ |
| Resistance ration | R ₂ /R ₁ | - | 8 | 10 | 12 | - |
| Transition frequency | f⊤ | V _{CE} =10V, I _E = −5mA, f=100MHz | - | 250 | - | MHz |

Absolute maximum rating@25°C

| Rating | Symbol | Value | Units |
|----------------------|----------------------|-------------|-------|
| Supply voltage | Vcc | 50 | V |
| Input voltage | V _{IN} | -5 to +30 | V |
| Output ourront | Io | 100 | mA |
| Output current | I _{C(MAX.)} | 100 | mA |
| Power dissipation | P _d | 150 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

Typical Characteristics

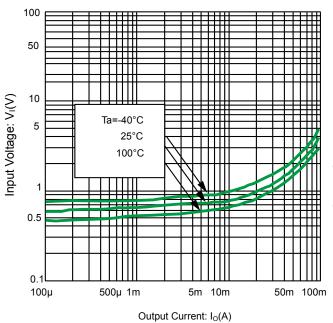


Fig 1.Input Voltage vs. output current

@V_O=0.3V (ON characteristics)

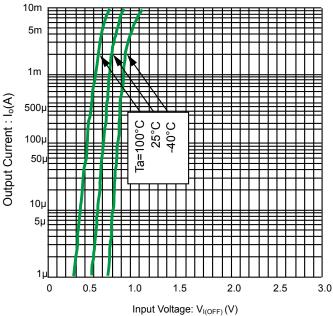
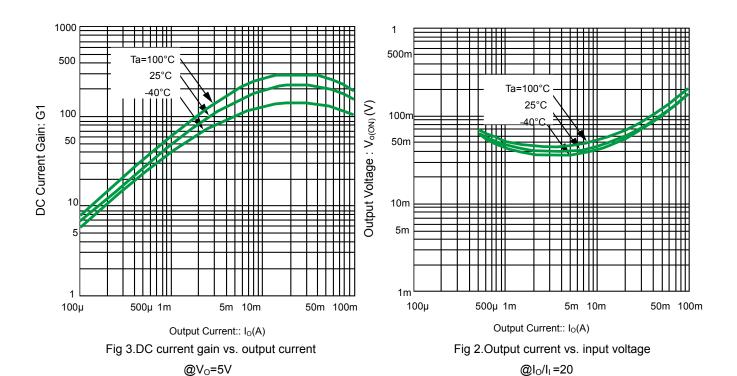
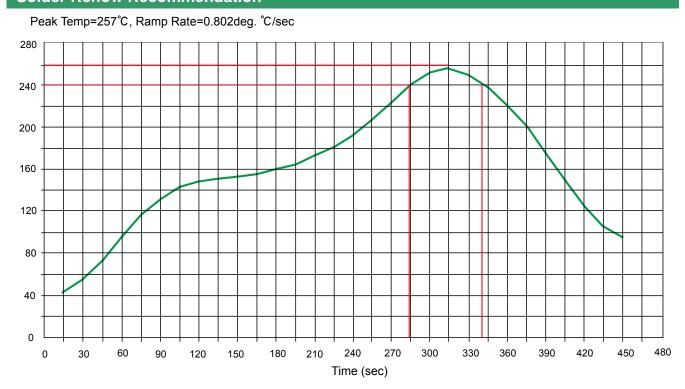


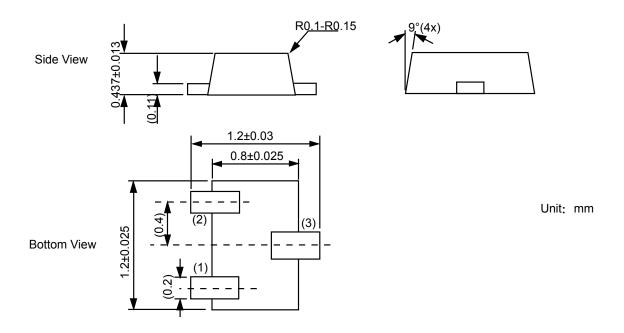
Fig 2.Output current vs. input voltage @V_{CC}=5V(OFF characteristics)

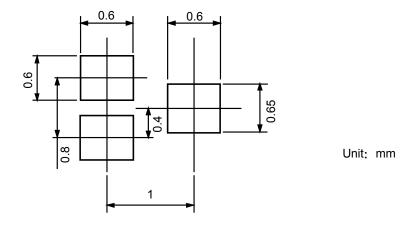


Solder Reflow Recommendation



Product dimension (SOT-723)





Ordering information

| Device | Package | Shipping | |
|-----------|-------------------|--------------------|--|
| PDTC143ZM | SOT-723 (Pb-Free) | 8000 / Tape & Reel | |

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